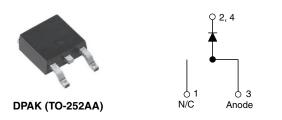
## VS-HFA08SD60S-M3

Vishay Semiconductors

## HEXFRED<sup>®</sup> Ultrafast Soft Recovery Diode, 8 A



PRIMARY CHARACTERISTICS								
I <sub>F(AV)</sub> 8 A								
V <sub>R</sub>	600 V							
V <sub>F</sub> at I <sub>F</sub>	1.4 V							
t <sub>rr</sub> typ.	18 ns							
T <sub>J</sub> max.	150 °C							
Package	DPAK (TO-252AA)							
Circuit configuration	Single							

#### FEATURES

- Ultrafast recovery time
- Ultrasoft recovery
- Very low I<sub>RRM</sub>
- Very low Q<sub>rr</sub>
- Guaranteed avalancheSpecified at operating conditions
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### BENEFITS

- Reduced RFI and EMI
- Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

#### **DESCRIPTION / APPLICATIONS**

These diodes are optimized to reduce losses and EMI / RFI in high frequency power conditioning systems. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for freewheeling, flyback, power converters, motor drives, and other applications where high speed and reduced switching losses are design requirements.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Cathode to anode voltage	V <sub>RRM</sub>		600	V						
Maximum continuous forward current	I <sub>F</sub>	T <sub>C</sub> = 100 °C	8							
Single pulse forward current	I <sub>FSM</sub>		60	A						
Peak repetitive forward current	I <sub>FRM</sub>		24							
Maximum power dissipation	PD	T <sub>C</sub> = 100 °C	14	W						
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +150	°C						

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-				
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 8 A		-	1.4	1.7	V		
		I <sub>F</sub> = 16 A	See fig. 1	-	1.7	2.1			
		I <sub>F</sub> = 8 A, T <sub>J</sub> = 125 °C		-	1.4	1.7			
Maximum reverse		$V_{R} = V_{R}$ rated	-	0.3	5.0				
leakage current	IR	$T_J = 125 \text{ °C}, V_R = 0.8 \text{ x } V_R \text{ rated}$	-	100	500	μA			
Junction capacitance	CT	V <sub>R</sub> = 200 V See fig. 3		-	10	25	pF		
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from pa	-	8.0	-	nH			

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 $^{\circ}$ C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS		
Reverse recovery time		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200$	-	18	-				
	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	37	55	ns		
		T <sub>J</sub> = 125 °C	I <sub>F</sub> = 8 A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 200 V	-	55	90			
Deal was a second	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	3.5	5.0	A nC		
Peak recovery current		T <sub>J</sub> = 125 °C		-	4.5	8.0			
Boyoroo roooyory oborgo	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	65	138			
Reverse recovery charge		T <sub>J</sub> = 125 °C		-	124	360			
Rate of fall of recovery current	dl <sub>(rec)M</sub> /dt	T <sub>J</sub> = 25 °C	]	-	240	-	A /uo		
		T <sub>J</sub> = 125 °C		-	210	-	A∕µs		

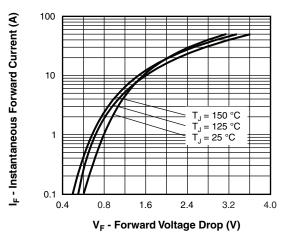
THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	150	°C			
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	3.5	°C/W			
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	80	C/W			
Weight			-	2.0	-	g			
weight			-	0.07	-	oz.			
Marking device		Case style DPAK (TO-252AA)		HFA08	SD60S				

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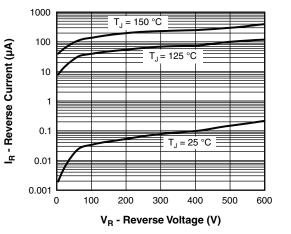
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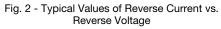


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Fig. 1 - Typical Forward Voltage Drop Characteristics





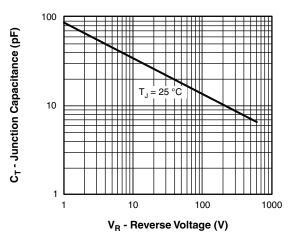
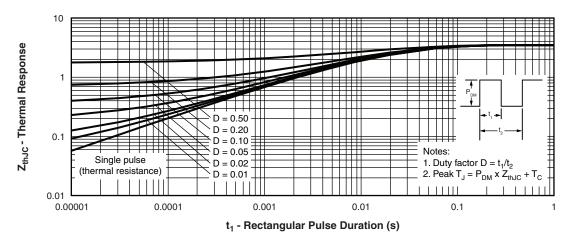
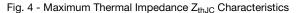


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage





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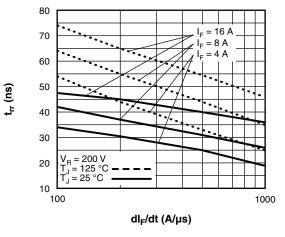


Fig. 5 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

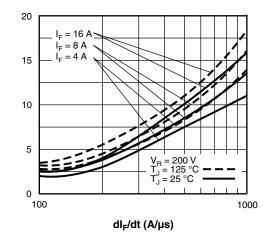


Fig. 6 - Typical Recovery Current vs. dl<sub>F</sub>/dt

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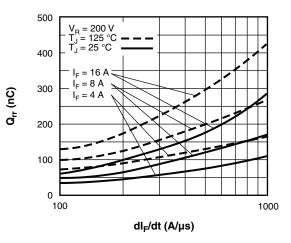


Fig. 7 - Typical Stored Charge vs. dl<sub>F</sub>/dt

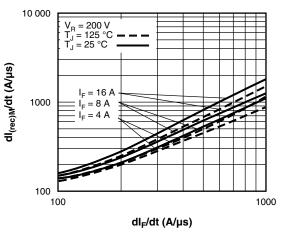


Fig. 8 - Typical  $dI_{(rec)M}/dt$  vs.  $dI_F/dt$ 

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I<sub>RR</sub> (A)

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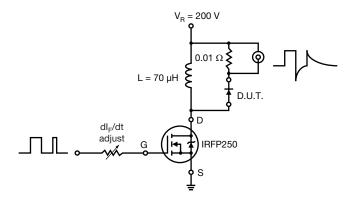


Fig. 9 - Reverse Recovery Parameter Test Circuit

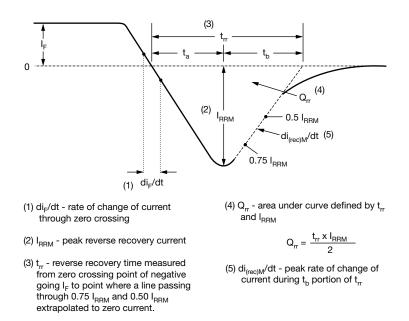


Fig. 10 - Reverse Recovery Waveform and Definitions

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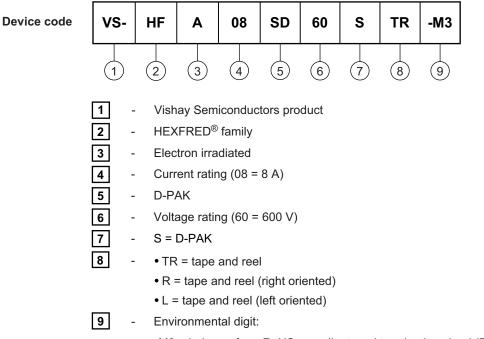
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#### ORDERING INFORMATION TABLE

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-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-HFA08SD60S-M3	75	3000	Antistatic plastic tube						
VS-HFA08SD60STR-M3	2000	2000	13" diameter reel						
VS-HFA08SD60SL-M3	3000	3000	13" diameter reel						
VS-HFA08SD60SR-M3	3000	3000	13" diameter reel						

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95627						
Part marking information	www.vishay.com/doc?95176						
Packaging information	www.vishay.com/doc?95033						

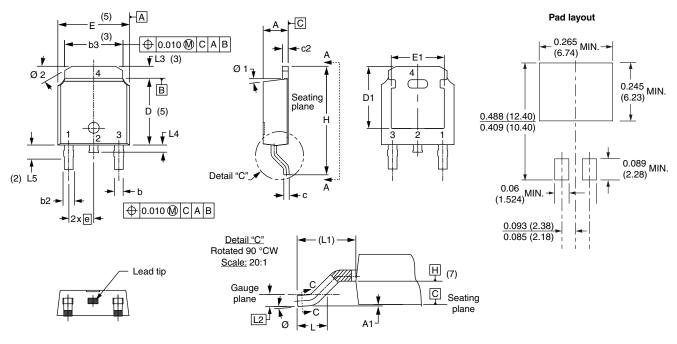


## **Outline Dimensions**

**Vishay Semiconductors** 

# D-PAK (TO-252AA) "M"

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIN	IETERS	INCHES		NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NUTES
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51 BSC		0.020 BSC		
С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5	]	Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3	]	Ø2	25°	35°	25°	35°	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Lead dimension uncontrolled in L5

<sup>(3)</sup> Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

- (6) Dimension b1 and c1 applied to base metal only
- <sup>(7)</sup> Datum A and B to be determined at datum plane H
- <sup>(8)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-252AA



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